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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	STM8
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	68
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	2.95V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8s207m8t6btr

Contents

1 Introduction 9

2 Description 10

3 Block diagram 12

4 Product overview 13

4.1 Central processing unit STM8 13

4.2 Single wire interface module (SWIM) and debug module (DM) 14

4.3 Interrupt controller 14

4.4 Flash program and data EEPROM memory 14

4.5 Clock controller 16

4.6 Power management 17

4.7 Watchdog timers 17

4.8 Auto wakeup counter 18

4.9 Beeper 18

4.10 TIM1 - 16-bit advanced control timer 18

4.11 TIM2, TIM3 - 16-bit general purpose timers 18

4.12 TIM4 - 8-bit basic timer 19

4.13 Analog-to-digital converter (ADC2) 19

4.14 Communication interfaces 19

4.14.1 UART1 20

4.14.2 UART3 20

4.14.3 SPI 21

4.14.4 I^2C 22

4.14.5 beCAN 22

5 Pinouts and pin description 23

5.1 Package pinouts 23

5.2 Alternate function remapping 32

6 Memory and register map 34

6.1 Memory map 34

List of figures

Figure 1. STM8S20xxx block diagram . . . 12
Figure 2. Flash memory organization . . . 15
Figure 3. LQFP 80-pin pinout . . . 23
Figure 4. LQFP 64-pin pinout . . . 24
Figure 5. LQFP 48-pin pinout . . . 25
Figure 6. LQFP 44-pin pinout . . . 26
Figure 7. LQFP 32-pin pinout . . . 27
Figure 8. Memory map . . . 34
Figure 9. Supply current measurement conditions . . . 52
Figure 10. Pin loading conditions . . . 53
Figure 11. Pin input voltage . . . 53
Figure 12. f_{CPUmax} versus V_{DD} . . . 57
Figure 13. External capacitor C_{EXT} . . . 57
Figure 14. Typ. $I_{DD(RUN)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz . . . 64
Figure 15. Typ. $I_{DD(WFI)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz . . . 64
Figure 16. HSE external clock source . . . 65
Figure 17. HSE oscillator circuit diagram . . . 66
Figure 18. Typical HSI frequency variation vs V_{DD} at 4 temperatures . . . 67
Figure 19. Typical LSI frequency variation vs V_{DD} @ 25 °C . . . 68
Figure 20. Typical V_{IL} and V_{IH} vs V_{DD} @ 4 temperatures . . . 71
Figure 21. Typical pull-up resistance vs V_{DD} @ 4 temperatures . . . 71
Figure 22. Typical pull-up current vs V_{DD} @ 4 temperatures . . . 72
Figure 23. Typ. V_{OL} @ V_{DD} = 5 V (standard ports) . . . 73
Figure 24. Typ. V_{OL} @ V_{DD} = 3.3 V (standard ports) . . . 73
Figure 25. Typ. V_{OL} @ V_{DD} = 5 V (true open drain ports) . . . 74
Figure 26. Typ. V_{OL} @ V_{DD} = 3.3 V (true open drain ports) . . . 74
Figure 27. Typ. V_{OL} @ V_{DD} = 5 V (high sink ports) . . . 75
Figure 28. Typ. V_{OL} @ V_{DD} = 3.3 V (high sink ports) . . . 75
Figure 29. Typ. V_{DD} - V_{OH} @ V_{DD} = 5 V (standard ports) . . . 76
Figure 30. Typ. V_{DD} - V_{OH} @ V_{DD} = 3.3 V (standard ports) . . . 76
Figure 31. Typ. V_{DD} - V_{OH} @ V_{DD} = 5 V (high sink ports) . . . 77
Figure 32. Typ. V_{DD} - V_{OH} @ V_{DD} = 3.3 V (high sink ports) . . . 77
Figure 33. Typical NRST V_{IL} and V_{IH} vs V_{DD} @ 4 temperatures . . . 78
Figure 34. Typical NRST pull-up resistance vs V_{DD} @ 4 temperatures . . . 79
Figure 35. Typical NRST pull-up current vs V_{DD} @ 4 temperatures . . . 79
Figure 36. Recommended reset pin protection . . . 79
Figure 37. SPI timing diagram - slave mode and CPHA = 0 . . . 81
Figure 38. SPI timing diagram - slave mode and CPHA = 1(1) . . . 81
Figure 39. SPI timing diagram - master mode(1) . . . 82
Figure 40. Typical application with I^2C bus and timing diagram . . . 84
Figure 41. ADC accuracy characteristics . . . 87
Figure 42. Typical application with ADC . . . 87
Figure 43. LQFP80 - 80-pin, 14 x 14 mm low-profile quad flat package outline . . . 92
Figure 44. LQFP80 recommended footprint . . . 93
Figure 45. LQFP80 marking example (package top view) . . . 94
Figure 46. LQFP64 - 64-pin 14 mm x 14 mm low-profile quad flat package outline . . . 95
Figure 47. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline . . . 96
Figure 48. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat recommended footprint . . . 97

Table 2. STM8S20xxx performance line features

Device	Pin count	Max. number of GPIOs (I/O)	Ext. interrupt pins	Timer CAPCOM channels	Timer complementary outputs	A/D converter channels	High sink I/Os	High density Flash program memory (bytes)	Data EEPROM (bytes	RAM (bytes)	beCAN interface
STM8S207MB	80	68	37	9	3	16	18	128 K	2048	6 K	
STM8S207M8	80	68	37	9	3	16	18	64 K	2048	6 K	
STM8S207RB	64	52	36	9	3	16	16	128 K	2048	6 K	
STM8S207R8	64	52	36	9	3	16	16	64 K	1536	6 K	
STM8S207R6	64	52	36	9	3	16	16	32 K	1024	6 K	
STM8S207CB	48	38	35	9	3	10	16	128 K	2048	6 K	
STM8S207C8	48	38	35	9	3	10	16	64 K	1536	6 K	No
STM8S207C6	48	38	35	9	3	10	16	32 K	1024	6 K	
STM8S207SB	44	34	31	8	3	9	15	128 K	1536	6 K	
STM8S207S8	44	34	31	8	3	9	15	64 K	1536	6 K	
STM8S207S6	44	34	31	8	3	9	15	32 K	1024	6 K	
STM8S207K8	32	25	23	8	3	7	12	64 K	1024	6 K	
STM8S207K6	32	25	23	8	3	7	12	32 K	1024	6 K	
STM8S208MB	80	68	37	9	3	16	18	128 K	2048	6 K	
STM8S208RB	64	52	37	9	3	16	16	128 K	2048	6 K	
STM8S208R8	64	52	37	9	3	16	16	64 K	2048	6 K	
STM8S208R6	64	52	37	9	3	16	16	32 K	2048	6 K	
STM8S208CB	48	38	35	9	3	10	16	128 K	2048	6 K	Yes
STM8S208C8	48	38	35	9	3	10	16	64 K	2048	6 K	
STM8S208C6	48	38	35	9	3	10	16	32 K	2048	6 K	
STM8S208SB	44	34	31	8	3	9	15	128 K	1536	6 K	
STM8S208S8	44	34	31	8	3	9	15	64 K	1536	6 K	
STM8S208S6	44	34	31	8	3	9	15	32 K	1536	6 K	

4.6 Power management

For efficient power management, the application can be put in one of four different low-power modes. You can configure each mode to obtain the best compromise between lowest power consumption, fastest start-up time and available wakeup sources.

- ***Wait mode***: In this mode, the CPU is stopped, but peripherals are kept running. The wakeup is performed by an internal or external interrupt or reset.
- ***Active halt mode with regulator on***: In this mode, the CPU and peripheral clocks are stopped. An internal wakeup is generated at programmable intervals by the auto wake up unit (AWU). The main voltage regulator is kept powered on, so current consumption is higher than in active halt mode with regulator off, but the wakeup time is faster. Wakeup is triggered by the internal AWU interrupt, external interrupt or reset.
- ***Active halt mode with regulator off:*** This mode is the same as active halt with regulator on, except that the main voltage regulator is powered off, so the wake up time is slower.
- ***Halt mode***: In this mode the microcontroller uses the least power. The CPU and peripheral clocks are stopped, the main voltage regulator is powered off. Wakeup is triggered by external event or reset.

4.7 Watchdog timers

The watchdog system is based on two independent timers providing maximum security to the applications.

Activation of the watchdog timers is controlled by option bytes or by software. Once activated, the watchdogs cannot be disabled by the user program without performing a reset.

Window watchdog timer

The window watchdog is used to detect the occurrence of a software fault, usually generated by external interferences or by unexpected logical conditions, which cause the application program to abandon its normal sequence.

The window function can be used to trim the watchdog behavior to match the application perfectly.

The application software must refresh the counter before time-out and during a limited time window.

A reset is generated in two situations:

1. Timeout: At 16 MHz CPU clock the time-out period can be adjusted between 75 µs up to 64 ms.
2. Refresh out of window: The downcounter is refreshed before its value is lower than the one stored in the window register.

Asynchronous communication (UART mode)

- Full duplex communication - NRZ standard format (mark/space)
- Programmable transmit and receive baud rates up to 1 Mbit/s (f_{CPU}/16) and capable of following any standard baud rate regardless of the input frequency
- Separate enable bits for transmitter and receiver
- Two receiver wakeup modes:
  - Address bit (MSB)
  - Idle line (interrupt)
- Transmission error detection with interrupt generation
- Parity control

LIN master capability

- Emission: Generates 13-bit sync break frame
- Reception: Detects 11-bit break frame

LIN slave mode

- Autonomous header handling - one single interrupt per valid message header
- Automatic baud rate synchronization - maximum tolerated initial clock deviation ±15%
- Sync delimiter checking
- 11-bit LIN sync break detection - break detection always active
- Parity check on the LIN identifier field
- LIN error management
- Hot plugging support

4.14.3 SPI

- Maximum speed: 10 Mbit/s (f_{MASTER}/2) both for master and slave
- Full duplex synchronous transfers
- Simplex synchronous transfers on two lines with a possible bidirectional data line
- Master or slave operation - selectable by hardware or software
- CRC calculation
- 1 byte Tx and Rx buffer
- Slave/master selection input pin

Table 6. Pin description (continued)

Pin number					Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
LQFP80	LQFP64	LQFP48	LQFP44	LQFP32			floating	wpu	Ext. interrupt	High sink	Speed	OD	PP			
69	55	39	35	-	PE1/I^{2}C_SCL	I/O	**X**		X		O1	T(3)		**Port E1**	I^{2}C clock	
70	56	40	36	-	PE0/CLK_CCO	I/O	**X**	X	X	HS	O3	X	X	**Port E0**	Configurable clock output	
71	-	-	-	-	PI6	I/O	**X**	X			O1	X	X	**Port I6**		
72	-	-	-	-	PI7	I/O	**X**	X			O1	X	X	**Port I7**		
73	57	41	37	25	PD0/TIM3_CH2	I/O	**X**	X	X	HS	O3	X	X	**Port D0**	Timer 3 - channel 2	TIM1_BKIN [AFR3]/ CLK_CCO [AFR2]
74	58	42	38	26	PD1/SWIM(4)	I/O	X	**X**	X	HS	O4	X	X	**Port D1**	SWIM data interface	
75	59	43	39	27	PD2/TIM3_CH1	I/O	**X**	X	X	HS	O3	X	X	**Port D2**	Timer 3 - channel 1	TIM2_CH3 [AFR1]
76	60	44	40	28	PD3/TIM2_CH2	I/O	**X**	X	X	HS	O3	X	X	**Port D3**	Timer 2 - channel 2	ADC_ETR [AFR0]
77	61	45	41	29	PD4/TIM2_CH1/BEEP	I/O	**X**	X	X	HS	O3	X	X	**Port D4**	Timer 2 - channel 1	BEEP output [AFR7]
78	62	46	42	30	PD5/ UART3_TX	I/O	**X**	X	X		O1	X	X	**Port D5**	UART3 data transmit	
79	63	47	43	31	PD6/ UART3_RX(1)	I/O	**X**	X	X		O1	X	X	**Port D6**	UART3 data receive	
80	64	48	44	32	PD7/TLI	I/O	**X**	X	X		O1	X	X	**Port D7**	Top level interrupt	TIM1_CH4 [AFR4](5)

1. The default state of UART1_RX and UART3_RX pins is controlled by the ROM bootloader. These pins are pulled up as part of the bootloader activation process and returned to the floating state before a return from the bootloader.
2. The beCAN interface is available on STM8S208xx devices only
3. In the open-drain output column, 'T' defines a true open-drain I/O (P-buffer, weak pull-up, and protection diode to V_{DD} are not implemented).
4. The PD1 pin is in input pull-up during the reset phase and after the internal reset release.
5. Available in 44-pin package only. On other packages, the AFR4 bit is reserved and must be kept at 0.

5.2 Alternate function remapping

As shown in the rightmost column of the pin description table, some alternate functions can be remapped at different I/O ports by programming one of eight AFR (alternate function

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 532B	TIM3	TIM3_ARRH	TIM3 auto-reload register high	0xFF
0x00 532C		TIM3_ARRL	TIM3 auto-reload register low	0xFF
0x00 532D		TIM3_CCR1H	TIM3 capture/compare register 1 high	0x00
0x00 532E		TIM3_CCR1L	TIM3 capture/compare register 1 low	0x00
0x00 532F		TIM3_CCR2H	TIM3 capture/compare register 2 high	0x00
0x00 5330		TIM3_CCR2L	TIM3 capture/compare register 2 low	0x00
0x00 5331 to 0x00 533F	Reserved area (15 bytes)			
0x00 5340	TIM4	TIM4_CR1	TIM4 control register 1	0x00
0x00 5341		TIM4_IER	TIM4 interrupt enable register	0x00
0x00 5342		TIM4_SR	TIM4 status register	0x00
0x00 5343		TIM4_EGR	TIM4 event generation register	0x00
0x00 5344		TIM4_CNTR	TIM4 counter	0x00
0x00 5345		TIM4_PSCR	TIM4 prescaler register	0x00
0x00 5346		TIM4_ARR	TIM4 auto-reload register	0xFF
0x00 5347 to 0x00 53FF	Reserved area (185 bytes)			
0x00 5400	ADC2	ADC _CSR	ADC control/status register	0x00
0x00 5401		ADC_CR1	ADC configuration register 1	0x00
0x00 5402		ADC_CR2	ADC configuration register 2	0x00
0x00 5403		ADC_CR3	ADC configuration register 3	0x00
0x00 5404		ADC_DRH	ADC data register high	0xXX
0x00 5405		ADC_DRL	ADC data register low	0xXX
0x00 5406		ADC_TDRH	ADC Schmitt trigger disable register high	0x00
0x00 5407		ADC_TDRL	ADC Schmitt trigger disable register low	0x00
0x00 5408 to 0x00 541F	Reserved area (24 bytes)			
0x00 5420	beCAN	CAN_MCR	CAN master control register	0x02
0x00 5421		CAN_MSR	CAN master status register	0x02
0x00 5422		CAN_TSR	CAN transmit status register	0x00
0x00 5423		CAN_TPR	CAN transmit priority register	0x0C
0x00 5424		CAN_RFR	CAN receive FIFO register	0x00
0x00 5425		CAN_IER	CAN interrupt enable register	0x00
0x00 5426		CAN_DGR	CAN diagnosis register	0x0C
0x00 5427		CAN_FPSR	CAN page selection register	0x00

10.3.2 Supply current characteristics

The current consumption is measured as described in *Figure 9 on page 52*.

Total current consumption in run mode

The MCU is placed under the following conditions:

- All I/O pins in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled (clock stopped by Peripheral Clock Gating registers) except if explicitly mentioned.
- When the MCU is clocked at 24 MHz, $T_A \leq 105$ °C and the WAITSTATE option bit is set.

Subject to general operating conditions for V_{DD} and T_A.

Table 20. Total current consumption with code execution in run mode at V_{DD} = 5 V

Symbol	Parameter	Conditions		Typ	Max	Unit
$I_{DD(RUN)}$	Supply current in run mode, code executed from RAM	$f_{CPU} = f_{MASTER}$ = 24 MHz, $T_A \leq$ 105 °C	HSE crystal osc. (24 MHz)	4.4		mA
			HSE user ext. clock (24 MHz)	3.7	7.3(1)	
		$f_{CPU} = f_{MASTER}$ = 16 MHz	HSE crystal osc. (16 MHz)	3.3		
			HSE user ext. clock (16 MHz)	2.7	5.8	
			HSI RC osc. (16 MHz)	2.5	3.4	
		$f_{CPU} = f_{MASTER}/128$ = 125 kHz	HSE user ext. clock (16 MHz)	1.2	4.1(1)	
			HSI RC osc. (16 MHz)	1.0	1.3(1)	
		$f_{CPU} = f_{MASTER}/128$ = 15.625 kHz	HSI RC osc. (16 MHz/8)	0.55		
		$f_{CPU} = f_{MASTER}$ = 128 kHz	LSI RC osc. (128 kHz)	0.45		
	Supply current in run mode, code executed from Flash	$f_{CPU} = f_{MASTER}$ = 24 MHz, $T_A \leq$ 105 °C	HSE crystal osc. (24 MHz)	11.4		
			HSE user ext. clock (24 MHz)	10.8	18(1)	
		$f_{CPU} = f_{MASTER}$ = 16 MHz	HSE crystal osc. (16 MHz)	9.0		
			HSE user ext. clock (16 MHz)	8.2	15.2(1)	
			HSI RC osc.(16 MHz)	8.1	13.2(1)	
		$f_{CPU} = f_{MASTER}$ = 2 MHz.	HSI RC osc. (16 MHz/8)(2)	1.5		
		$f_{CPU} = f_{MASTER}/128$ = 125 kHz	HSI RC osc. (16 MHz)	1.1		
		$f_{CPU} = f_{MASTER}/128$ = 15.625 kHz	HSI RC osc. (16 MHz/8)	0.6		
		$f_{CPU} = f_{MASTER}$ = 128 kHz	LSI RC osc. (128 kHz)	0.55		

1. Data based on characterization results, not tested in production.
2. Default clock configuration measured with all peripherals off.

Total current consumption and timing in forced reset state

Table 29. Total current consumption and timing in forced reset state

Symbol	Parameter	Conditions	Typ	Max(1)	Unit
$I_{DD(R)}$	Supply current in reset state	V_{DD} = 5 V	1.6		mA
		V_{DD} = 3.3 V	0.8		
$t_{RESETBL}$	Reset release to bootloader vector fetch			150	µs

1. Data guaranteed by design, not tested in production.

Current consumption of on-chip peripherals

Subject to general operating conditions for V_{DD} and T_A.

HSI internal RC/f_{CPU} = f_{MASTER} = 16 MHz.

Table 30. Peripheral current consumption

Symbol	Parameter	Typ.	Unit
$I_{DD(TIM1)}$	TIM1 supply current (1)	220	µA
$I_{DD(TIM2)}$	TIM2 supply current (1)	120	
$I_{DD(TIM3)}$	TIM3 timer supply current (1)	100	
$I_{DD(TIM4)}$	TIM4 timer supply current (1)	25	
$I_{DD(UART1)}$	UART1 supply current (2)	90	
$I_{DD(UART3)}$	UART3 supply current (2)	110	
$I_{DD(SPI)}$	SPI supply current (2)	40	
$I_{DD(I^2C)}$	I^2C supply current (2)	50	
$I_{DD(CAN)}$	beCAN supply current (2)	210	
$I_{DD(ADC2)}$	ADC2 supply current when converting (3)	1000	

1. Data based on a differential I_{DD} measurement between reset configuration and timer counter running at 16 MHz. No IC/OC programmed (no I/O pads toggling). Not tested in production.
2. Data based on a differential I_{DD} measurement between the on-chip peripheral when kept under reset and not clocked and the on-chip peripheral when clocked and not kept under reset. No I/O pads toggling. Not tested in production.
3. Data based on a differential I_{DD} measurement between reset configuration and continuous A/D conversions. Not tested in production.

Current consumption curves

Figure 14 and *Figure 15* show typical current consumption measured with code executing in RAM.

Figure 14. Typ. $I_{DD(RUN)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz

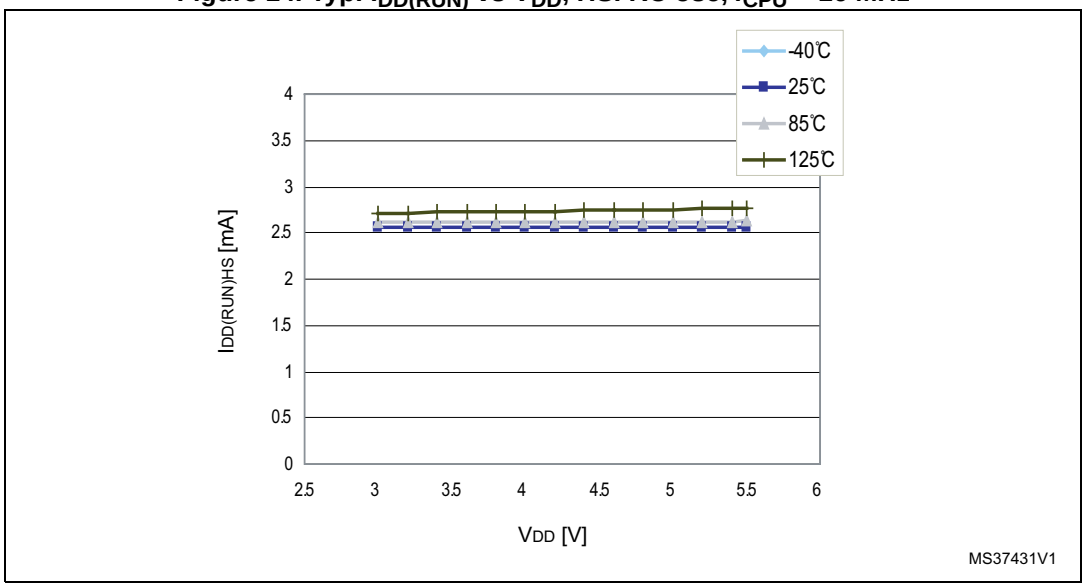


Figure 15. Typ. $I_{DD(WFI)}$ vs V_{DD}, HSI RC osc, f_{CPU} = 16 MHz

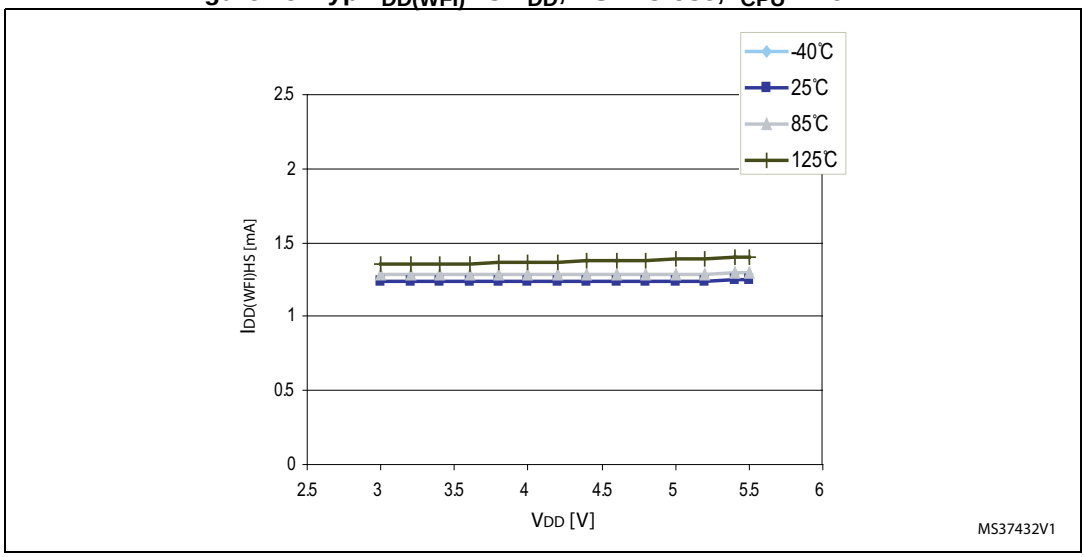
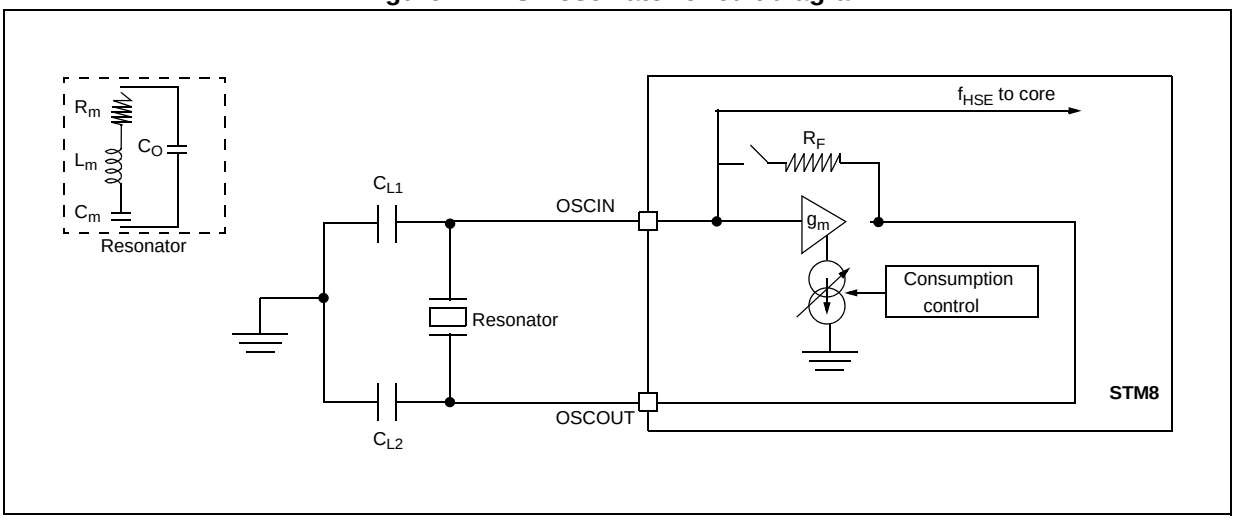


Table 32. HSE oscillator characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSE}	External high speed oscillator frequency		1		24	MHz
R_F	Feedback resistor			220		kΩ
$C^{(1)}$	Recommended load capacitance (2)				20	pF
$I_{DD(HSE)}$	HSE oscillator power consumption	C = 20 pF, f_{OSC} = 24 MHz			6 (startup) 2 (stabilized)(3)	mA
		C = 10 pF, f_{OSC} = 24 MHz			6 (startup) 1.5 (stabilized)(3)	
g_m	Oscillator transconductance		5			mA/V
$t_{SU(HSE)}^{(4)}$	Startup time	V_{DD} is stabilized		1		ms

1. C is approximately equivalent to 2 x crystal Cload.
2. The oscillator selection can be optimized in terms of supply current using a high quality resonator with small R_m value. Refer to crystal manufacturer for more details
3. Data based on characterization results, not tested in production.
4. $t_{SU(HSE)}$ is the start-up time measured from the moment it is enabled (by software) to a stabilized 24 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

Figure 17. HSE oscillator circuit diagram



HSE oscillator critical g_m formula

$$g_{mcrit} = (2 \times \Pi \times f_{HSE})^2 \times R_m(2Co + C)^2$$

R_m: Notional resistance (see crystal specification)
L_m: Notional inductance (see crystal specification)
C_m: Notional capacitance (see crystal specification)
Co: Shunt capacitance (see crystal specification)
C_{L1}=C_{L2}=C: Grounded external capacitance
$g_m >> g_{mcrit}$

Low speed internal RC oscillator (LSI)

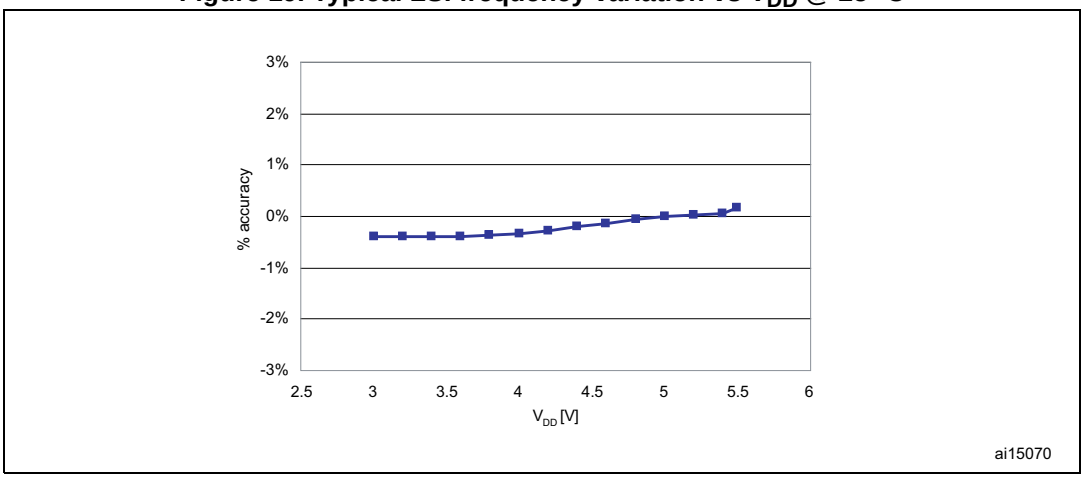
Subject to general operating conditions for V_{DD} and T_A.

Table 34. LSI oscillator characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{LSI}	Frequency		110	128	146	kHz
$t_{su(LSI)}$	LSI oscillator wakeup time				7(1)	µs
$I_{DD(LSI)}$	LSI oscillator power consumption			5		µA

1. Guaranteed by design, not tested in production.

Figure 19. Typical LSI frequency variation vs V_{DD} @ 25 °C



10.3.5 Memory characteristics

RAM and hardware registers

Table 35. RAM and hardware registers

Symbol	Parameter	Conditions	Min	Unit
V_{RM}	Data retention mode(1)	Halt mode (or reset)	V_{IT-max}(2)	V

1. Minimum supply voltage without losing data stored in RAM (in halt mode or under reset) or in hardware registers (only in halt mode). Guaranteed by design, not tested in production.
2. Refer to *Table 19 on page 57* for the value of V_{IT-max}.

Flash program memory/data EEPROM memory

General conditions: T_A = -40 to 125 °C.

Table 36. Flash program memory/data EEPROM memory

Symbol	Parameter	Conditions	Min(1)	Typ	Max	Unit
V_{DD}	Operating voltage (all modes, execution/write/erase)	$f_{CPU} \leq$ 24 MHz	2.95		5.5	V
t_{prog}	Standard programming time (including erase) for byte/word/block (1 byte/4 bytes/128 bytes)			6	6.6	ms
	Fast programming time for 1 block (128 bytes)			3	3.3	ms
t_{erase}	Erase time for 1 block (128 bytes)			3	3.3	ms
N_{RW}	Erase/write cycles(2) (program memory)	T_A = 85 °C	10 k			cycles
	Erase/write cycles (data memory)(2)	T_A = 125 ° C	300 k	1M		
t_{RET}	Data retention (program memory) after 10 k erase/write cycles at T_A = 85 °C	T_{RET} = 55° C	20			years
	Data retention (data memory) after 10 k erase/write cycles at T_A = 85 °C	T_{RET} = 55° C	20			
	Data retention (data memory) after 300k erase/write cycles at T_A = 125 °C	T_{RET} = 85° C	1			
I_{DD}	Supply current (Flash programming or erasing for 1 to 128 bytes)			2		mA

1. Data based on characterization results, not tested in production.
2. The physical granularity of the memory is 4 bytes, so cycling is performed on 4 bytes even when a write/erase operation addresses a single byte.

Figure 34. Typical NRST pull-up resistance vs V_{DD} @ 4 temperatures

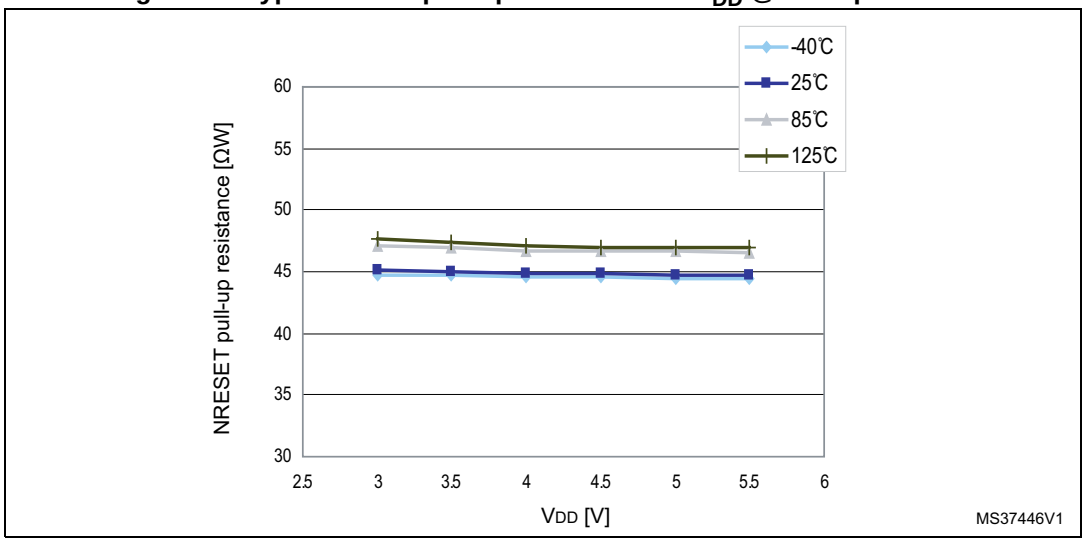
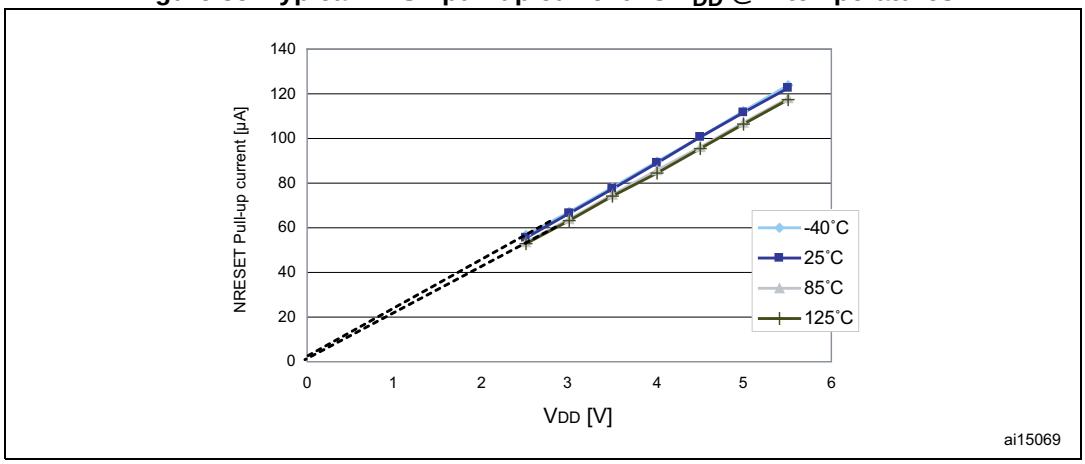
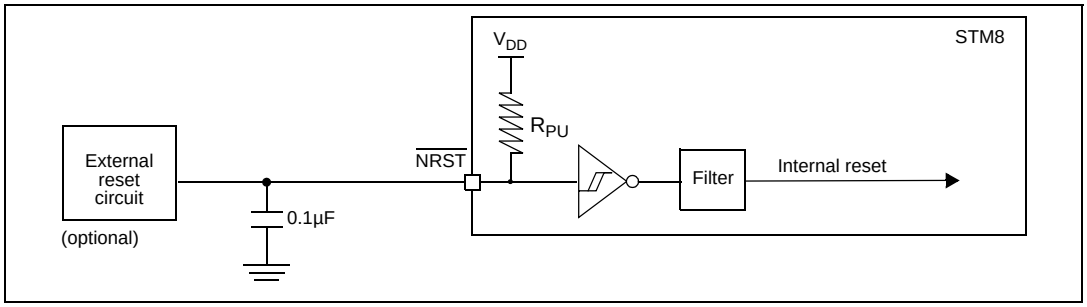


Figure 35. Typical NRST pull-up current vs V_{DD} @ 4 temperatures



The reset network shown in *Figure 36* protects the device against parasitic resets. The user must ensure that the level on the NRST pin can go below the V_{IL} max. level specified in *Table 41*. Otherwise the reset is not taken into account internally. For power consumption sensitive applications, the capacity of the external reset capacitor can be reduced to limit charge/discharge current. If the NRSTsignal is used to reset the external circuitry, care must be taken of the charge/discharge time of the external capacitor to fulfill the external device's reset timing conditions. The minimum recommended capacity is 10 nF.

Figure 36. Recommended reset pin protection



10.3.10 10-bit ADC characteristics

Subject to general operating conditions for V_{DDA}, f_{MASTER}, and T_A unless otherwise specified.

Table 44. ADC characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{ADC}	ADC clock frequency	V_{DDA} = 3 to 5.5 V	1		4	MHz
		V_{DDA} = 4.5 to 5.5 V	1		6	
V_{DDA}	Analog supply		3		5.5	V
V_{REF+}	Positive reference voltage		2.75(1)		V_{DDA}	V
V_{REF-}	Negative reference voltage		V_{SSA}		0.5(1)	V
V_{AIN}	Conversion voltage range(2)		V_{SSA}		V_{DDA}	V
		Devices with external V_{REF+}/V_{REF-} pins	V_{REF-}		V_{REF+}	V
C_{ADC}	Internal sample and hold capacitor			3		pF
t_S(2)	Sampling time	f_{ADC} = 4 MHz	0.75			µs
		f_{ADC} = 6 MHz	0.5			
t_{STAB}	Wakeup time from standby			7		µs
t_{CONV}	Total conversion time (including sampling time, 10-bit resolution)	f_{ADC} = 4 MHz	3.5			µs
		f_{ADC} = 6 MHz	2.33			µs
			14			$1/f_{ADC}$

1. Data guaranteed by design, not tested in production.
2. During the sample time the input capacitance C_{AIN} (3 pF max) can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_S. After the end of the sample time t_S, changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_S depend on programming.

Table 52. LQFP64 - 64-pin, 14 x 14 mm low-profile quad flat package mechanical data (continued)

Symbol	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
k	0.0 °	3.5 °	7.0 °	0.0 °	3.5 °	7.0 °
ccc			0.100			0.0039

1. Values in inches are converted from mm and rounded to four decimal places.

Figure 47. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline

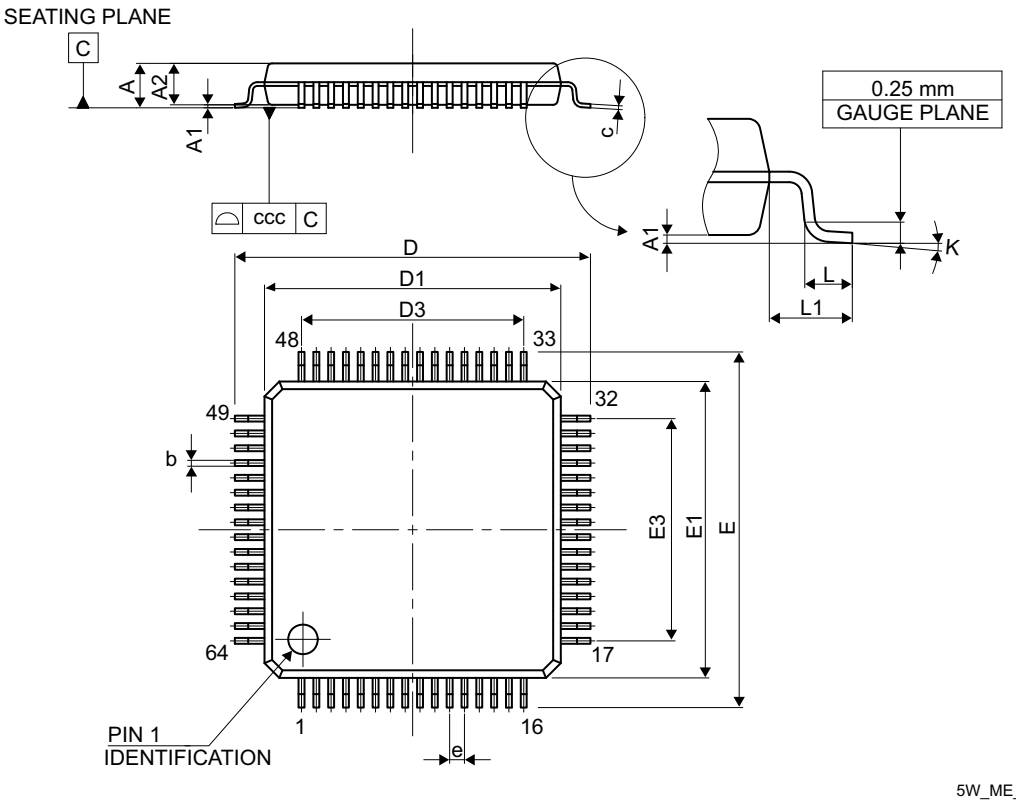
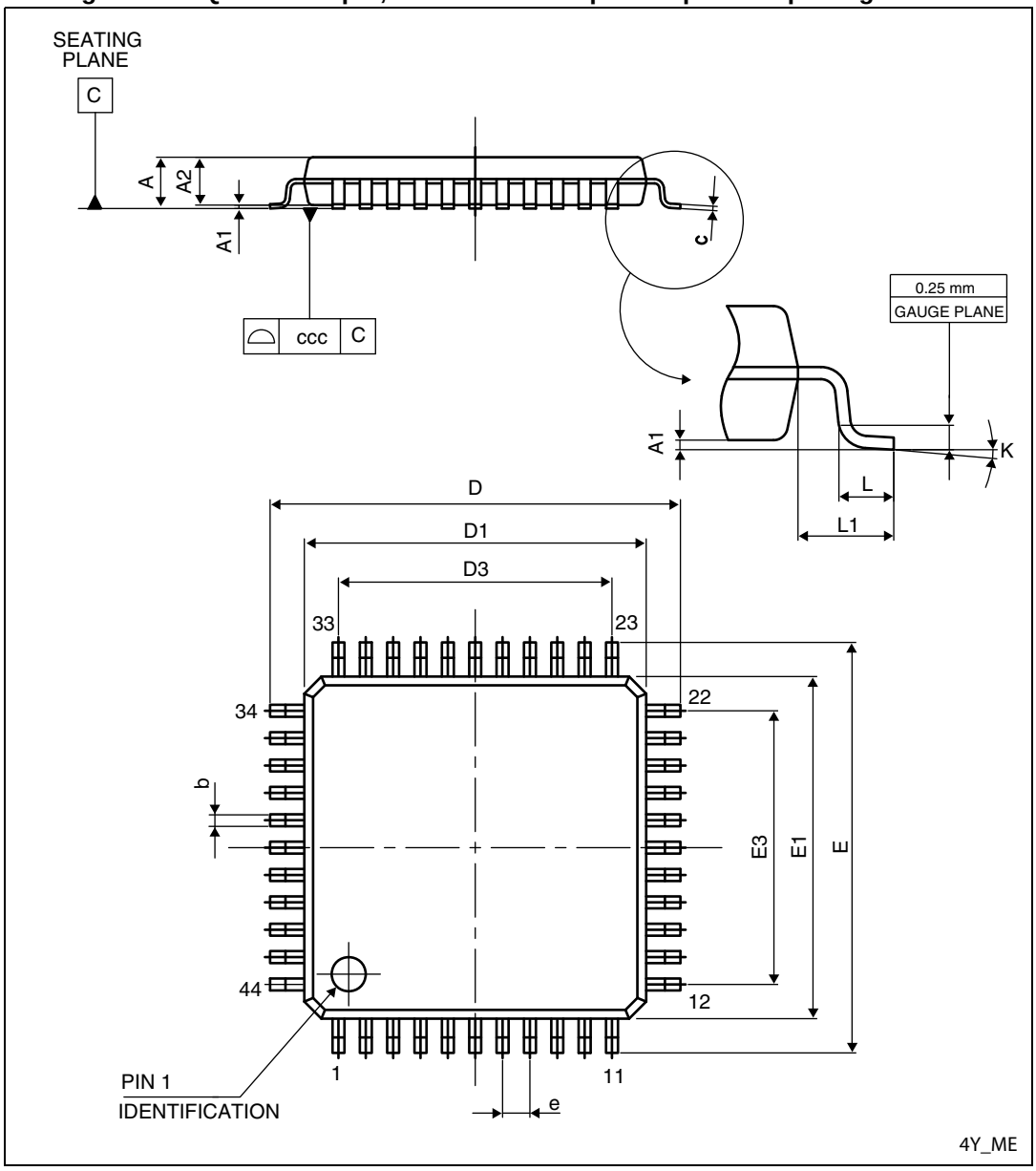


Table 53. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data

Symbol	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079

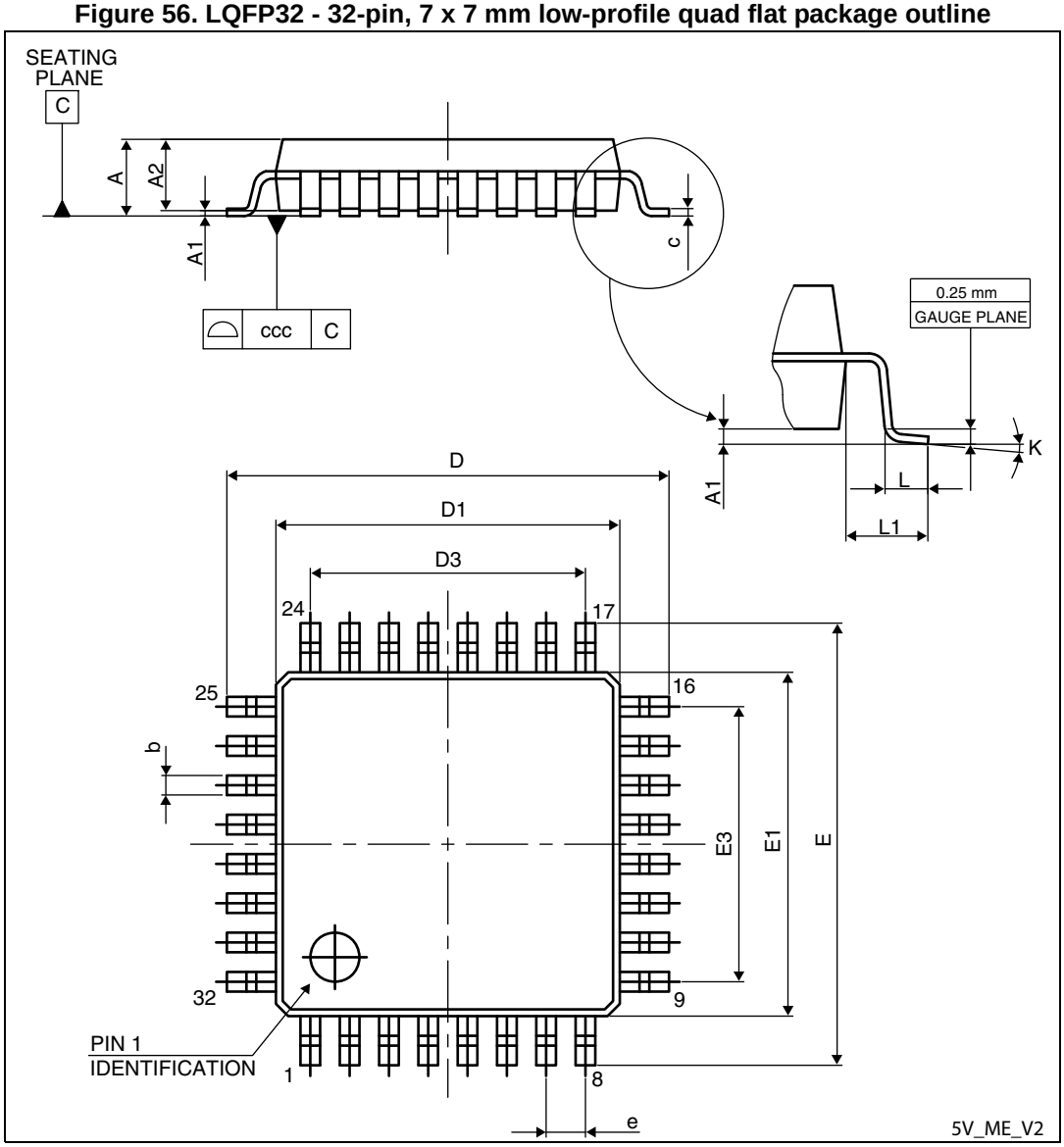
11.1.4 LQFP44 package information

Figure 53. LQFP44 - 44-pin, 10 x 10 mm low-profile quad flat package outline



11.1.5 LQFP32 package information

Figure 56. LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat package outline



11.2 Thermal characteristics

The maximum chip junction temperature (T_{Jmax}) must never exceed the values given in *Table 18: General operating conditions on page 56*.

The maximum chip-junction temperature, T_{Jmax}, in degrees Celsius, may be calculated using the following equation:

$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$

Where:

- T_{Amax} is the maximum ambient temperature in °C
- Θ_{JA} is the package junction-to-ambient thermal resistance in ° C/W
- P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$)
- P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.
- $P_{I/Omax}$ represents the maximum power dissipation on output pins, where: $P_{I/Omax} = \Sigma (V_{OL}*I_{OL}) + \Sigma((V_{DD}-V_{OH})*I_{OH})$, and taking account of the actual V_{OL}/I_{OL} and V_{OH}/I_{OH} of the I/Os at low and high level in the application.

Table 57. Thermal characteristics(1)

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP 80 - 14 x 14 mm	38	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 64 - 14 x 14 mm	45	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 64 - 10 x 10 mm	46	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 48 - 7 x 7 mm	57	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 44 - 10 x 10 mm	54	°C/W
Θ_{JA}	Thermal resistance junction-ambient LQFP 32 - 7 x 7 mm	60	°C/W

1. Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

11.2.1 Reference document

JESD51-2 integrated circuits thermal test method environment conditions - natural convection (still air). Available from www.jedec.org.

12.2 Software tools

STM8 development tools are supported by a complete, free software package from STMicroelectronics that includes ST Visual Develop (STVD) IDE and the ST Visual Programmer (STVP) software interface. STVD provides seamless integration of the Cosmic and Raisonance C compilers for STM8. A free version that outputs up to 32 Kbytes of code is available.

12.2.1 STM8 toolset

STM8 toolset with STVD integrated development environment and STVP programming software is available for free download at *www.st.com/mcu*. This package includes:

ST Visual Develop – Full-featured integrated development environment from ST, featuring

- Seamless integration of C and ASM toolsets
- Full-featured debugger
- Project management
- Syntax highlighting editor
- Integrated programming interface
- Support of advanced emulation features for STice such as code profiling and coverage

ST Visual Programmer (STVP) – Easy-to-use, unlimited graphical interface allowing read, write and verification of the STM8 microcontroller Flash program memory, data EEPROM and option bytes. STVP also offers project mode for saving programming configurations and automating programming sequences.

12.2.2 C and assembly toolchains

Control of C and assembly toolchains is seamlessly integrated into the STVD integrated development environment, making it possible to configure and control the building of the application directly from an easy-to-use graphical interface.

Available toolchains include:

- ***Cosmic C compiler for STM8*** – One free version that outputs up to 32 Kbytes of code is available. For more information, see www.cosmic-software.com.
- ***Raisonance C compiler for STM8*** – One free version that outputs up to 32 Kbytes of code. For more information, see www.raisonance.com.
- ***STM8 assembler linker*** – Free assembly toolchain included in the STVD toolset, which allows you to assemble and link the application source code.

12.3 Programming tools

During the development cycle, STice provides in-circuit programming of the STM8 Flash microcontroller on the application board via the SWIM protocol. Additional tools are to include a low-cost in-circuit programmer as well as ST socket boards, which provide dedicated programming platforms with sockets for programming the STM8.

For production environments, programmers will include a complete range of gang and automated programming solutions from third-party tool developers already supplying programmers for the STM8 family.